

32-bit ARM Cortex-M0 microcontroller; 64 kB flash and 8 kB SRAM; 12-bit ADC

Rev. 1 — 24 February 2015

**Product data sheet** 

## 1. General description

The LPC112x are a ARM Cortex-M0 based, low-cost 32-bit MCU family, designed for 8/16-bit microcontroller applications, offering performance, low power, simple instruction set and memory addressing together with reduced code size compared to existing 8/16-bit architectures.

The LPC112x operate at CPU frequencies of up to 50 MHz.

The peripheral complement of the LPC112x includes 64 kB of flash memory, 8 kB of data memory, one Fast-mode Plus I<sup>2</sup>C-bus interface, three RS-485/EIA-485 UARTs, two SSP interfaces, four general purpose counter/timers, a 12-bit ADC, and up to 38 general purpose I/O pins.

## 2. Features and benefits

- System:
  - ◆ ARM Cortex-M0 processor, running at frequencies of up to 50 MHz.
  - ARM Cortex-M0 built-in Nested Vectored Interrupt Controller (NVIC).
  - Non-Maskable Interrupt (NMI) input selectable from several input sources.
  - Serial Wire Debug.
  - System tick timer.
- Memory:
  - ◆ 64 kB on-chip flash programming memory.
  - 256 byte page erase function.
  - 8 kB SRAM.
  - In-System Programming (ISP) and In-Application Programming (IAP) via on-chip bootloader software.
- Digital peripherals:
  - Up to 38 General Purpose I/O (GPIO) pins with configurable pull-up/pull-down resistors. A configurable open-drain mode is supported.
  - GPIO pins can be used as edge and level sensitive interrupt sources.
  - High-current output driver (20 mA) on one pin.
  - High-current sink drivers (20 mA) on two I<sup>2</sup>C-bus pins in Fast-mode Plus.
  - Four general purpose counter/timers with up to six capture inputs and up to 13 match outputs.
  - Programmable windowed WDT.
- Analog peripherals:
  - ◆ 12-bit ADC with 2 Msamples/s and eight channels.



- Serial interfaces:
  - Three UARTs with fractional baud rate generation, internal FIFO, and RS-485 support. One UART with modem control.
  - Two SSP controllers with FIFO and multi-protocol capabilities.
  - I<sup>2</sup>C-bus interface supporting full I<sup>2</sup>C-bus specification and Fast-mode Plus with a data rate of 1 Mbit/s with multiple address recognition and monitor mode.
- Clock generation:
  - ◆ 12 MHz internal RC oscillator trimmed to 1 % accuracy for -25 °C ≤ T<sub>amb</sub> ≤ +85 °C that can optionally be used as a system clock.
  - Crystal oscillator with an operating range of 1 MHz to 25 MHz.
  - Programmable watchdog oscillator with a frequency range of 9.4 kHz to 2.3 MHz.
  - PLL allows CPU operation up to the maximum CPU rate without the need for a high-frequency crystal. May be run from the system oscillator or the internal RC oscillator.
  - Clock output function with divider that can reflect the system oscillator clock, IRC clock, CPU clock, and the Watchdog clock.
- Power control:
  - Integrated PMU (Power Management Unit) to minimize power consumption during Sleep, Deep-sleep, and Deep power-down modes.
  - Power profiles residing in boot ROM allowing to optimize performance and minimize power consumption for any given application through one simple function call.
  - Three reduced power modes: Sleep, Deep-sleep, and Deep power-down.
  - Processor wake-up from Deep-sleep mode via a dedicated start logic using up to 13 of the functional pins.
  - Power-On Reset (POR).
  - Brownout detect with up to four separate thresholds for interrupt and forced reset.
- Unique device serial number for identification.
- Single power supply (1.8 V to 3.6 V).
- Available as LQFP48 package.

## 3. Applications

- eMetering
- Alarm systems

- Lighting
- White goods

## 4. Ordering information

Table 1. Ordering infor	mation						
Type number	Package						
	Name	Description					
LPC1125JBD48/303	LQFP48	LQFP48: plastic low profile quad flat package; 48 leads; body 7 $\times$ 7 $\times$ 1.4 mm					
LPC1124JBD48/303	LQFP48	LQFP48: plastic low profile quad flat package; 48 leads; body 7 $\times$ 7 $\times$ 1.4 mm					

LPC112x

Version SOT313-2

SOT313-2

## 4.1 Ordering options

#### Table 2.Ordering options

Type number	Flash	Total SRAM	UART RS-485	l <sup>2</sup> C/ Fast+	SSP	ADC channels	GPIO	Package
LPC1125JBD48/303	64 kB	8 kB	3	1	2	8	38	LQFP48
LPC1124JBD48/303	32 kB	8 kB	3	1	2	8	38	LQFP48

#### 32-bit ARM Cortex-M0 microcontroller

#### **Block diagram** 5.



#### **Pinning information** 6.

## 6.1 Pinning

## LPC112x

#### 32-bit ARM Cortex-M0 microcontroller



## 6.2 Pin description

Symbol	LQFP48		Reset state [1]	Start logic wake-up pin	Туре	Description
RESET/PIO0_0	3	[8]	I; PU	yes	I	<b>RESET</b> — External reset input: A LOW-going pulse as short as 50 ns on this pin resets the device, causing I/O ports and peripherals to take on their default states, and processor execution to begin at address 0
					I/O	<b>PIO0_0</b> — General purpose port 0 input/output 0.
PIO0_1	4	<u>[6]</u>	I; PU	yes	I/O	<b>PIO0_1</b> — General purpose port 0 input/output 1. A LOW level on this pin during reset starts the ISP command handler.
					0	CLKOUT — Clock output.
					0	CT32B0_MAT2 — Match output 2 for 32-bit timer 0.
PIO0_2	10	[6]	I; PU	yes	I/O	PIO0_2 — General purpose port 0 input/output 2.
					I/O	SSP0_SSEL — Slave select for SSP0.
					I	CT16B0_CAP0 — Capture input 0 for 16-bit timer 0.
					I	ADC_PIN_TRIG0 — ADC pin trigger input 0.
PIO0_3	14	[6]	I; PU	yes	I/O	PIO0_3 — General purpose port 0 input/output 3.
					-	R — Reserved.
					-	R — Reserved.
			I	U2_RXD — Receiver input for UART2.		
PIO0_4	15		I; IA	yes	I/O	PIO0_4 — General purpose port 0 input/output 4.
					I/O	<b>I2C0_SCL</b> — I <sup>2</sup> C-bus, open-drain clock input/output. High-current sink only if I <sup>2</sup> C Fast-mode Plus is selected in the I/O configuration register.
PIO0_5	16	[7]	I; IA	yes	I/O	PIO0_5 — General purpose port 0 input/output 5.
					I/O	<b>I2C0_SDA</b> — I <sup>2</sup> C-bus, open-drain data input/output. High-current sink only if I <sup>2</sup> C Fast-mode Plus is selected in the I/O configuration register.
PIO0_6	22	[6]	I; PU	yes	I/O	PIO0_6 — General purpose port 0 input/output 6.
					-	R — Reserved.
					I/O	SSP0_SCK — Serial clock for SSP0.
					0	U1_TXD — Transmitter output for UART1.
PIO0_7	23	<u>[5]</u>	I; PU	yes	I/O	<b>PIO0_7</b> — General purpose port 0 input/output 7. High-current output driver.
					I	<b>U0_CTS</b> — Clear To Send input for UART0.
					I	ADC_PIN_TRIG1 — ADC pin trigger input 1.
					I	<b>U1_RXD</b> — Receiver input for UART1.
PIO0_8	26	<u>[6]</u>	I; PU	yes	I/O	PIO0_8 — General purpose port 0 input/output 8.
					I/O	SSP0_MISO — Master In Slave Out for SSP0.
					0	CT16B0_MAT0 — Match output 0 for 16-bit timer 0.
					-	R — Reserved.
					I	ADC_PIN_TRIG2 — ADC pin trigger input 2.

## LPC112x

## 32-bit ARM Cortex-M0 microcontroller

Symbol	LQFP48		Reset state [1]	Start logic wake-up pin	Туре	Description
PIO0_9	27	[6]	I; PU	yes	I/O	PIO0_9 — General purpose port 0 input/output 9.
					I/O	SSP0_MOSI — Master Out Slave In for SSP0.
					0	CT16B0_MAT1 — Match output 1 for 16-bit timer 0.
					-	R — Reserved.
					I	ADC_PIN_TRIG3 — ADC pin trigger input 3.
SWCLK/PIO0_10	28	[6]	I; PU	yes	I/O	SWCLK — Serial wire clock.
					I/O	PIO0_10 — General purpose port 0 input/output 10.
					I/O	SSP0_SCK — Serial clock for SSP0.
					0	CT16B0_MAT2 — Match output 2 for 16-bit timer 0.
R/PIO0_11	30	<u>[3]</u>	I; PU	yes	1	<b>R</b> — Reserved. Configure for an alternate function in the IOCON block.
					I/O	PIO0_11 — General purpose port 0 input/output 11.
					AI	ADC_7 — A/D converter, input 7.
			0	CT32B0_MAT3 — Match output 3 for 32-bit timer 0.		
R/PIO1_0	31 🗳	<u>[3]</u>	I; PU	yes	1	<b>R</b> — Reserved. Configure for an alternate function in the IOCON block.
					I/O	PIO1_0 — General purpose port 1 input/output 0.
					AI	ADC_6 — A/D converter, input 6.
					I	CT32B1_CAP0 — Capture input 0 for 32-bit timer 1.
R/PIO1_1	32	[3]	O; PU	no	0	<b>R</b> — Reserved. Configure for an alternate function in the IOCON block.
					I/O	PIO1_1 — General purpose port 1 input/output 1.
					AI	ADC_5 — A/D converter, input 5.
					0	CT32B1_MAT0 — Match output 0 for 32-bit timer 1.
R/PIO1_2	35	[3]	I; PU	no	I	<b>R</b> — Reserved. Configure for an alternate function in the IOCON block.
					I/O	PIO1_2 — General purpose port 1 input/output 2.
					AI	ADC_4 — A/D converter, input 4.
					0	CT32B1_MAT1 — Match output 1 for 32-bit timer 1.
SWDIO/PIO1_3	38	8 [3]	I; PU	no	I/O	<b>SWDIO</b> — Serial Wire Debug I/O. SWDIO is enabled by default on this pin.
					I/O	PIO1_3 — General purpose port 1 input/output 3.
					AI	ADC_3 — A/D converter, input 3.
					0	CT32B1_MAT2 — Match output 2 for 32-bit timer 1.

#### Table 3.Pin description

## LPC112x

## 32-bit ARM Cortex-M0 microcontroller

Symbol	LQFP48		Reset state [1]	Start logic wake-up pin	Туре	Description
PIO1_4/ WAKEUP	39	<u>[4]</u>	I; PU	no	IO	<b>PIO1_4</b> — General purpose port 1 input/output 4. General-purpose digital input/output pin. This pin also serves as the Deep power-down mode wake-up pin with 20 ns glitch filter. Pull this pin HIGH externally before entering Deep power-down mode. Pull this pin LOW to exit Deep power-down mode. A LOW-going pulse as short as 50 ns wakes up the part.
					AI	ADC_2 — A/D converter, input 2.
					0	CT32B1_MAT3 — Match output 3 for 32-bit timer 1.
PIO1_5	45	<u>[6]</u>	I; PU	no	I/O	<b>PIO1_5</b> — General purpose port 1 input/output 5.
					0	<b>U0_RTS</b> — Request To Send output for UART0.
					I	CT32B0_CAP0 — Capture input 0 for 32-bit timer 0.
PIO1_6	46	<u>[6]</u>	I; PU	no	I/O	<b>PIO1_6</b> — General purpose port 1 input/output 6.
					I	<b>U0_RXD</b> — Receiver input for UART0. In ISP mode, connect to UART.
					0	CT32B0_MAT0 — Match output 0 for 32-bit timer 0.
PIO1_7	47	[6]	I; PU	no	I/O	PIO1_7 — General purpose port 1 input/output 7.
					0	<b>U0_TXD</b> — Transmitter output for UART0. In ISP mode, connect to UART.
					0	CT32B0_MAT1 — Match output 1 for 32-bit timer 0.
PIO1_8	9	[6]	I; PU	no	I/O	PIO1_8 — General purpose port 1 input/output 8.
					I	CT16B1_CAP0 — Capture input 0 for 16-bit timer 1.
					-	R — Reserved.
					0	U2_TXD — Transmitter output for U2.
PIO1_9	17	[6]	I; PU	no	I/O	PIO1_9 — General purpose port 1 input/output 9.
					0	CT16B1_MAT0 — Match output 0 for 16-bit timer 1.
					I/O	SSP1_MOSI — Master Out Slave In for SSP1.I
PIO1_10	29	[3]	I; PU	no	I/O	PIO1_10 — General purpose port 1 input/output 10.
					AI	ADC_8 — A/D converter, input 8.
					0	CT16B1_MAT1 — Match output 1 for 16-bit timer 1.
					I/O	SSP1_MISO — Master In Slave Out for SSP1.
PIO1_11	42	[3]	I; PU	no	I/O	PIO1_11 — General purpose port 1 input/output 11.
					AI	ADC_1 — A/D converter, input 1.
					I	CT32B1_CAP1 — Capture input 1 for 32-bit timer 1.
PIO2_0	2	[6]	I; PU	no	ю	PIO2_0 — General purpose port 2 input/output 0.
					0	<b>U0_DTR</b> — Data Terminal Ready output for UART0.
					I/O	SSP1_SSEL — Slave Select for SSP1.
					I	ADC_PIN_TRIG4 — ADC pin trigger input 4.
PIO2_1	13	[6]	I; PU	no	I/O	PIO2_1 — General purpose port 2 input/output 1.
					I	U0_DSR — Data Set Ready input for UART0.
					I/O	SSP1_SCK — Serial clock for SSP1.

#### Table 3. Pin description

Table 3. Pin description

## **LPC112x**

## 32-bit ARM Cortex-M0 microcontroller

Symbol	LQFP48		Reset state [1]	Start logic wake-up pin	Туре	Description
PIO2_2	25	<u>[6]</u>	I; PU	no	I/O	<b>PIO2_2</b> — General purpose port 2 input/output 2.
					I	<b>U0_DCD</b> — Data Carrier Detect input for UART0.
					I/O	SSP1_MISO — Master In Slave Out for SSP1.
PIO2_3	37	[6]	I; PU	no	I/O	PIO2_3 — General purpose port 2 input/output 3.
					I	<b>U0_RI</b> — Ring Indicator input for UART0.
					I/O	SSP1_MOSI — Master Out Slave In for SSP1.
PIO2_4	19	[6]	I; PU	no	I/O	PIO2_4 — General purpose port 2 input/output 4.
					0	CT16B1_MAT1 — Match output 1 for 16-bit timer 1.
					I/O	SSP1_SSEL — Slave Select for SSP1.
PIO2_5	20	[6]	I; PU	no	I/O	PIO2_5 — General purpose port 2 input/output 5.
					0	CT32B0_MAT0 — Match output 0 for 32-bit timer 0.
PIO2_6	1	<u>[6]</u>	I; PU	no	I/O	PIO2_6 — General purpose port 2 input/output 6.
					0	CT32B0_MAT1 — Match output 1 for 32-bit timer 0.
PIO2_7	11	<u>[6]</u>	I; PU	no	I/O	PIO2_7 — General purpose port 2 input/output 7.
					0	CT32B0_MAT2 — Match output 2 for 32-bit timer 0.
					I	U0_RXD — Receiver input for UART0.
PIO2_8	12	[6]	I; PU	no	I/O	PIO2_8 — General purpose port 2 input/output 8.
					I	CT32B0_MAT3 — Match output 3 for 32-bit timer 0.
					0	U0_TXD — Transmitter output for UART0.
PIO2_9	24	[6]	I; PU	no	I/O	PIO2_9 — General purpose port 2 input/output 9.
					I	CT32B0_CAP0 — Capture input 0 for 32-bit timer 0.
PIO2_10	-	<u>[6]</u>	I: PU	no	I/O	PIO2_10 — General purpose port 2 input/output 10.
PIO3_0	36	[6]	I; PU	no	I/O	PIO3_0 — General purpose port 3 input/output 0.
					0	<b>U0_DTR</b> — Data Terminal Ready output for UART0.
					0	CT16B0_MAT0 — Match output 0 for 16-bit timer 0.
					0	U0_TXD — Transmitter Output for UART0.
PIO3_2	-	[6]	I; PU	no	I/O	PIO3_2 — General purpose port 3 input/output 2.
					I	<b>U0_DCD</b> — Data Carrier Detect input for UART0.
					0	CT16B0_MAT2 — Match output 2 for 16-bit timer 0.
					I/O	SSP1_SCK — Serial clock for SSP1.
PIO3_3	48	[6]	I; PU	no	I/O	PIO3_3 — General purpose port 3 input/output 3.
					I	<b>U0_RI</b> — Ring Indicator input for UART0.
					I	CT16B0_CAP0 — Capture input 0 for 16-bit timer 0.
PIO3_4	18	[6]	I; PU	no	I/O	PIO3_4 — General purpose port 3 input/output 4.
					I	CT16B0_CAP1 — Capture input 1 for 16-bit timer 0.
					I	<b>U0_RXD</b> — Receiver input for UART0.
PIO3_5	21	[6]	I; PU	no	I/O	PIO3_5 — General purpose port 3 input/output 5.
					I	CT16B1_CAP1 — Capture input 1 for 16-bit timer 1.
					0	<b>U0_TXD</b> — Transmitter output for UART0.

Symbol	LQFP48		Reset state [1]	Start logic wake-up pin	Туре	Description
XTALIN	6	[2]	-	-	-	Input to the oscillator circuit and internal clock generator circuits. Input voltage must not exceed 1.8 V.
XTALOUT	7	[2]	-	-	-	Output from the oscillator amplifier.
VREFP	33		-	-	-	Positive reference voltage for the ADC.
VREFN	34		-	-	-	Negative reference voltage for the ADC.
V <sub>DD</sub>	8; 44		-	-	-	3.3 V supply voltage to the internal regulator and the external rail.
V <sub>DDA</sub>	43		-	-	-	Analog supply voltage.
V <sub>SSA</sub>	40		-	-	-	Analog ground.
V <sub>SS</sub>	5; 41		-	-	-	Ground.

#### Table 3. Pin description

- [1] Pin state at reset for default function: I = Input; AI = Analog Input; O = Output; PU = internal pull-up enabled (pins pulled up to full V<sub>DD</sub> level (V<sub>DD</sub> = 3.3 V)); IA = inactive, no pull-up/down enabled.
- [2] When the system oscillator is not used, connect XTALIN and XTALOUT as follows: XTALIN can be left floating or can be grounded (grounding is preferred to reduce susceptibility to noise). XTALOUT should be left floating.
- [3] 5 V tolerant pad providing digital I/O functions with configurable pull-up/pull-down resistors, configurable hysteresis, and analog input. When configured as a ADC input, digital section of the pad is disabled and the pin is not 5 V tolerant (see Figure 27).
- [4] Pad providing digital I/O functions with configurable pull-up/pull-down resistors, configurable hysteresis, and analog input. When configured as a ADC input, digital section of the pad is disabled (see <u>Figure 27</u>). In deep power-down mode, this pin serves as the wake-up pin.
- [5] High-current output driver. Pad providing digital I/O functions with configurable pull-up/pull-down resistors and configurable hysteresis (see Figure 27).
- [6] Standard digital I/O pin. Pad providing digital I/O functions with configurable pull-up/pull-down resistors and configurable hysteresis (see Figure 27).
- [7] I<sup>2</sup>C-bus pins compliant with the I<sup>2</sup>C-bus specification for I<sup>2</sup>C standard mode, I<sup>2</sup>C Fast-mode, and I<sup>2</sup>C Fast-mode Plus. The pin requires an external pull-up to provide output functionality. When power is switched off, this pin is floating and does not disturb the I<sup>2</sup>C lines. Open-drain configuration applies to all functions on this pin.
- [8] 5 V tolerant pad. RESET functionality is not available in Deep power-down mode. Use the WAKEUP pin to reset the chip and wake up from Deep power-down mode. An external pull-up resistor is required on this pin for the Deep power-down mode. See Figure 28 for the reset pad configuration.

## 7. Functional description

### 7.1 ARM Cortex-M0 processor

The ARM Cortex-M0 is a general purpose, 32-bit microprocessor, which offers high performance and very low power consumption.

## 7.2 On-chip flash program memory

The LPC112x contain up to 64 kB of on-chip flash memory.

## 7.3 On-chip SRAM

The LPC112x contain a total of 8 kB on-chip static RAM memory.

## 7.4 Memory map

The LPC112x incorporate several distinct memory regions, shown in the following figures. Figure 3 shows the overall map of the entire address space from the user program viewpoint following reset. The interrupt vector area supports address remapping.

The AHB peripheral area is 2 MB in size, and is divided to allow for up to 128 peripherals. The APB peripheral area is 512 kB in size and is divided to allow for up to 32 peripherals. Each peripheral of either type is allocated 16 kB of space. This allows simplifying the address decoding for each peripheral.

#### 32-bit ARM Cortex-M0 microcontroller

**NXP Semiconductors** 



## 7.5 Nested Vectored Interrupt Controller (NVIC)

The Nested Vectored Interrupt Controller (NVIC) is an integral part of the Cortex-M0. The tight coupling to the CPU allows for low interrupt latency and efficient processing of late arriving interrupts.

#### 7.5.1 Features

• Controls system exceptions and peripheral interrupts.

LPC112x

- On the LPC112x, the NVIC supports 32 vectored interrupts including up to 13 inputs to the start logic from individual GPIO pins.
- Four programmable interrupt priority levels with hardware priority level masking.
- Software interrupt generation.

#### 7.5.2 Interrupt sources

Each peripheral device has one interrupt line connected to the NVIC but may have several interrupt flags. Individual interrupt flags may also represent more than one interrupt source.

Any GPIO pin (total of up to 40 pins) regardless of the selected function, can be programmed to generate an interrupt on a level, or rising edge or falling edge, or both.

## 7.6 IOCON block

The IOCON block allows selected pins of the microcontroller to have more than one function. Configuration registers control the multiplexers to allow connection between the pin and the on-chip peripherals.

Peripherals should be connected to the appropriate pins prior to being activated and prior to any related interrupt(s) being enabled. Activity of any enabled peripheral function that is not mapped to a related pin should be considered undefined.

## 7.7 Fast general purpose parallel I/O

Device pins that are not connected to a specific peripheral function are controlled by the GPIO registers. Pins may be dynamically configured as inputs or outputs. Multiple outputs can be set or cleared in one write operation.

LPC112x use accelerated GPIO functions:

- GPIO registers are a dedicated AHB peripheral so that the fastest possible I/O timing can be achieved.
- Entire port value can be written in one instruction.

Additionally, any GPIO pin (total of 38 pins) providing a digital function can be programmed to generate an interrupt on a level, a rising or falling edge, or both.

#### 7.7.1 Features

- Bit level port registers allow a single instruction to set or clear any number of bits in one write operation.
- Direction control of individual bits.
- All I/O default to inputs with pull-ups enabled after reset with the exception of the I<sup>2</sup>C-bus pins PIO0\_4 and PIO0\_5.
- Pull-up/pull-down resistor configuration can be programmed through the IOCON block for each GPIO pin (except for pins PIO0\_4 and PIO0\_5).
- All GPIO pins (except PIO0\_4 and PIO0\_5) are pulled up to 3.3 V (V<sub>DD</sub> = 3.3 V) if their pull-up resistor is enabled in the IOCON block.
- Programmable open-drain mode.

### 7.8 UART

The LPC112x contain three UARTs.

Support for RS-485/9-bit mode allows both software address detection and automatic address detection using 9-bit mode.

The UART includes a fractional baud rate generator. Standard baud rates such as 115200 Bd can be achieved with any crystal frequency above 2 MHz.

#### 7.8.1 Features

- Maximum UART data bit rate of 3.125 MBit/s.
- 16 Byte Receive and Transmit FIFOs.
- Register locations conform to 16C550 industry standard.
- Receiver FIFO trigger points at 1 B, 4 B, 8 B, and 14 B.
- Built-in fractional baud rate generator covering wide range of baud rates without a need for external crystals of particular values.
- FIFO control mechanism that enables software flow control implementation.
- Support for RS-485/9-bit mode.
- Support for modem control.

### 7.9 SSP controller

The LPC112x contains two SSP controllers.

The SSP controller is capable of operation on a SSP, 4-wire SSI, or Microwire bus. It can interact with multiple masters and slaves on the bus. Only a single master and a single slave can communicate on the bus during a given data transfer. The SSP supports full duplex transfers, with frames of 4 bits to 16 bits of data flowing from the master to the slave and from the slave to the master. In practice, often only one of these data flows carries meaningful data.

### 7.9.1 Features

- Maximum SSP speed of 25 Mbit/s (master) or 4.17 Mbit/s (slave) (in SSP mode).
- Compatible with Motorola SPI, 4-wire Texas Instruments SSI, and National Semiconductor Microwire buses.
- Synchronous serial communication.
- Master or slave operation.
- 8-frame FIFOs for both transmit and receive.
- 4-bit to 16-bit frame.

#### 7.10 I<sup>2</sup>C-bus serial I/O controller

The LPC112x contains one I<sup>2</sup>C-bus controller.

The I<sup>2</sup>C-bus is bidirectional for inter-IC control using only two wires: a Serial Clock Line (SCL) and a Serial DAta line (SDA). Each device is recognized by a unique address and can operate as either a receiver-only device (e.g., an LCD driver) or a transmitter with the

capability to both receive and send information (such as memory). Transmitters and/or receivers can operate in either master or slave mode, depending on whether the chip has to initiate a data transfer or is only addressed. The I<sup>2</sup>C is a multi-master bus and can be controlled by more than one bus master connected to it.

#### 7.10.1 Features

- The I<sup>2</sup>C-interface is a standard I<sup>2</sup>C-bus compliant interface with open-drain pins. The I<sup>2</sup>C-bus interface also supports Fast-mode Plus with bit rates up to 1 Mbit/s.
- Easy to configure as master, slave, or master/slave.
- Programmable clocks allow versatile rate control.
- Bidirectional data transfer between masters and slaves.
- Multi-master bus (no central master).
- Arbitration between simultaneously transmitting masters without corruption of serial data on the bus.
- Serial clock synchronization allows devices with different bit rates to communicate via one serial bus.
- Serial clock synchronization can be used as a handshake mechanism to suspend and resume serial transfer.
- The I<sup>2</sup>C-bus can be used for test and diagnostic purposes.
- The I<sup>2</sup>C-bus controller supports multiple address recognition and a bus monitor mode.

## 7.11 Analog-to-Digital Converter (ADC)

The ADC supports a resolution of 12 bit and fast conversion rates of up to 2 Msamples/s. Sequences of analog-to-digital conversions can be triggered by multiple sources. Possible trigger sources are internal connections to the 16-bit timer match outputs, five external pins, and the ARM TXEV interrupt.

The ADC includes a hardware threshold compare function with zero-crossing detection.

#### 7.11.1 Features

- 12-bit successive approximation analog to digital converter.
- 12-bit conversion rate of 2 Msamples/s.
- Input multiplexing among 8 pins.
- Two configurable conversion sequences with independent triggers.
- Optional automatic high/low threshold comparison and zero-crossing detection.
- Power-down mode and low-power operating mode.
- Measurement range VREFN to VREFP (typically 3 V; not to exceed VDDA voltage level).
- Burst conversion mode for single or multiple inputs.

#### 7.12 General purpose external event counter/timers

The LPC112x include two 32-bit counter/timers and two 16-bit counter/timers. The counter/timer is designed to count cycles of the system derived clock. It can optionally generate interrupts or perform other actions at specified timer values, based on four match registers. Each counter/timer also includes up to two capture inputs to trap the timer value when an input signal transitions, optionally generating an interrupt.

#### 7.12.1 Features

- A 32-bit/16-bit timer/counter with a programmable 32-bit/16-bit prescaler.
- Counter or timer operation.
- Up to two capture channels per timer, that can take a snapshot of the timer value when an input signal transitions. A capture event may also generate an interrupt.
- The timer and prescaler may be configured to be cleared on a designated capture event. This feature permits easy pulse width measurement by clearing the timer on the leading edge of an input pulse and capturing the timer value on the trailing edge.
- Four match registers per timer that allow:
  - Continuous operation with optional interrupt generation on match.
  - Stop timer on match with optional interrupt generation.
  - Reset timer on match with optional interrupt generation.
- Up to four external outputs corresponding to match registers, with the following capabilities:
  - Set LOW on match.
  - Set HIGH on match.
  - Toggle on match.
  - Do nothing on match.

#### 7.13 System tick timer

The ARM Cortex-M0 includes a system tick timer (SYSTICK) that is intended to generate a dedicated SYSTICK exception at a fixed time interval (typically 10 ms).

#### 7.14 Windowed WatchDog Timer

The purpose of the watchdog is to reset the controller if software fails to periodically service it within a programmable time window.

#### 7.14.1 Features

- Internally resets chip if not periodically reloaded during the programmable time-out period.
- Optional windowed operation requires reload to occur between a minimum and maximum time period, both programmable.
- Optional warning interrupt can be generated at a programmable time prior to watchdog time-out.
- Enabled by software but requires a hardware reset or a watchdog reset/interrupt to be disabled.

LPC112x

© NXP Semiconductors N.V. 2015. All rights reserved.

- Incorrect feed sequence causes reset or interrupt if enabled.
- Flag to indicate watchdog reset.
- Programmable 24-bit timer with internal prescaler.
- Selectable time period from  $(T_{cy(WDCLK)} \times 256 \times 4)$  to  $(T_{cy(WDCLK)} \times 2^{24} \times 4)$  in multiples of  $T_{cy(WDCLK)} \times 4$ .
- The Watchdog Clock (WDCLK) source can be selected from the IRC or the dedicated watchdog oscillator (WDO). This gives a wide range of potential timing choices of watchdog operation under different power conditions.

## 7.15 Clocking and power control

### 7.15.1 Crystal oscillators

The LPC112x include three independent oscillators. These are the system oscillator, the Internal RC oscillator (IRC), and the Watchdog oscillator. Each oscillator can be used for more than one purpose as required in a particular application.

Following reset, the LPC112x will operate from the Internal RC oscillator until switched by software. This allows systems to operate without any external crystal and the bootloader code to operate at a known frequency.

See Figure 4 for an overview of the LPC112x clock generation.

## LPC112x

#### 32-bit ARM Cortex-M0 microcontroller



#### 7.15.1.1 Internal RC oscillator

The IRC may be used as the clock source for the WDT, and/or as the clock that drives the PLL and subsequently the CPU. The nominal IRC frequency is 12 MHz.

Upon power-up or any chip reset, the LPC112x use the IRC as the clock source. Software may later switch to one of the other available clock sources.

#### 7.15.1.2 System oscillator

The system oscillator can be used as the clock source for the CPU, with or without using the PLL.

The system oscillator operates at frequencies of 1 MHz to 25 MHz. This frequency can be boosted to a higher frequency, up to the maximum CPU operating frequency, by the system PLL.

#### 7.15.1.3 Watchdog oscillator

The watchdog oscillator can be used as a clock source that directly drives the CPU, the watchdog timer, or the CLKOUT pin. The watchdog oscillator nominal frequency is programmable between 9.4 kHz and 2.3 MHz. The frequency spread over processing and temperature is  $\pm$ 40 %.

#### 7.15.2 System PLL

The PLL accepts an input clock frequency in the range of 10 MHz to 25 MHz. The input frequency is multiplied up to a high frequency with a Current Controlled Oscillator (CCO). The multiplier can be an integer value from 1 to 32. The CCO operates in the range of 156 MHz to 320 MHz, so there is an additional divider in the loop to keep the CCO within its frequency range while the PLL is providing the desired output frequency. The PLL output frequency must be lower than 100 MHz. The output divider may be set to divide by 2, 4, 8, or 16 to produce the output clock. Since the minimum output divider value is 2, it is insured that the PLL output has a 50 % duty cycle. The PLL is turned off and bypassed following a chip reset and may be enabled by software. The program must configure and activate the PLL, wait for the PLL to lock, and then connect to the PLL as a clock source. The PLL settling time is 100  $\mu$ s.

#### 7.15.3 Clock output

The LPC112x features a clock output function that routes the IRC oscillator, the system oscillator, the watchdog oscillator, or the main clock to an output pin.

#### 7.15.4 Wake-up process

The LPC112x begin operation at power-up and when awakened from Deep power-down mode by using the 12 MHz IRC oscillator as the clock source. This allows chip operation to resume quickly. If the system oscillator or the PLL is needed by the application, software will need to enable these features and wait for them to stabilize before they are used as a clock source.

#### 7.15.5 Power control

The LPC112x support a variety of power control features. There are three special modes of processor power reduction: Sleep mode, Deep-sleep mode, and Deep power-down mode. The CPU clock rate may also be controlled as needed by changing clock sources, reconfiguring PLL values, and/or altering the CPU clock divider value. This allows a trade-off of power versus processing speed based on application requirements. In addition, a register is provided for shutting down the clocks to individual on-chip peripherals, allowing fine tuning of power consumption by eliminating all dynamic power use in any peripherals that are not required for the application. Selected peripherals have their own clock divider which provides even better power control.

#### 7.15.5.1 Power profiles

The power consumption in Active and Sleep modes can be optimized for the application through simple calls to the power profile. The power configuration routine configures the LPC112x for one of the following power modes:

- Default mode corresponding to power configuration after reset.
- · CPU performance mode corresponding to optimized processing capability.

- Efficiency mode corresponding to optimized balance of current consumption and CPU performance.
- Low-current mode corresponding to lowest power consumption.

In addition, the power profile includes routines to select the optimal PLL settings for a given system clock and PLL input clock.

#### 7.15.5.2 Sleep mode

When Sleep mode is entered, the clock to the core is stopped. Resumption from the Sleep mode does not need any special sequence but re-enabling the clock to the ARM core.

In Sleep mode, execution of instructions is suspended until either a reset or interrupt occurs. Peripheral functions continue operation during Sleep mode and may generate interrupts to cause the processor to resume execution. Sleep mode eliminates dynamic power used by the processor itself, memory systems and related controllers, and internal buses.

#### 7.15.5.3 Deep-sleep mode

In Deep-sleep mode, the chip is in Sleep mode, and in addition all analog blocks are shut down. As an exception, the user has the option to keep the watchdog oscillator and the BOD circuit running for self-timed wake-up and BOD protection. Deep-sleep mode allows for additional power savings.

Up to 13 pins total serve as external wake-up pins to the start logic to wake up the chip from Deep-sleep mode.

Unless the watchdog oscillator is selected to run in Deep-sleep mode, the clock source should be switched to IRC before entering Deep-sleep mode, because the IRC can be switched on and off glitch-free.

#### 7.15.5.4 Deep power-down mode

In Deep power-down mode, power is shut off to the entire chip with the exception of the WAKEUP pin. The LPC112x can wake up from Deep power-down mode via the WAKEUP pin.

A LOW-going pulse as short as 50 ns wakes up the part from Deep power-down mode.

When entering Deep power-down mode, an external pull-up resistor is required on the WAKEUP pin to hold it HIGH. The RESET pin must also be held HIGH to prevent it from floating while in Deep power-down mode.

## 7.16 System control

#### 7.16.1 Start logic

The start logic connects external pins to corresponding interrupts in the NVIC. Each pin shown in <u>Table 3</u> as input to the start logic has an individual interrupt in the NVIC interrupt vector table. The start logic pins can serve as external interrupt pins when the chip is running. In addition, an input signal on the start logic pins can wake up the chip from Deep-sleep mode when all clocks are shut down.

The start logic must be configured in the system configuration block and in the NVIC before being used.

All information provided in this document is subject to legal disclaimers.

#### 7.16.2 Reset

Reset has four sources on the LPC112x: the RESET pin, the Watchdog reset, Power-On Reset (POR), and the BrownOut Detection (BOD) circuit. The RESET pin is a Schmitt trigger input pin. Assertion of chip reset by any source, once the operating voltage attains a usable level, starts the IRC and initializes the flash controller.

A LOW-going pulse as short as 50 ns resets the part.

When the internal Reset is removed, the processor begins executing at address 0, which is initially the Reset vector mapped from the boot block. At that point, all of the processor and peripheral registers have been initialized to predetermined values.

An external pull-up resistor is required on the RESET pin if Deep power-down mode is used.

#### 7.16.3 Brownout detection

The LPC112x includes up to four levels for monitoring the voltage on the V<sub>DD</sub> pin. If this voltage falls below one of the selected levels, the BOD asserts an interrupt signal to the NVIC. This signal can be enabled for interrupt in the Interrupt Enable Register in the NVIC in order to cause a CPU interrupt; if not, software can monitor the signal by reading a dedicated status register. Four threshold levels can be selected to cause a forced reset of the chip.

#### 7.16.4 Code security (Code Read Protection - CRP)

This feature of the LPC112x allows user to enable different levels of security in the system so that access to the on-chip flash and use of the Serial Wire Debugger (SWD) and In-System Programming (ISP) can be restricted. When needed, CRP is invoked by programming a specific pattern into a dedicated flash location. IAP commands are not affected by the CRP.

In addition, ISP entry via the PIO0\_1 pin can be disabled without enabling CRP. For details see the *LPC111x user manual*.

There are three levels of Code Read Protection:

- CRP1 disables access to the chip via the SWD and allows partial flash update (excluding flash sector 0) using a limited set of the ISP commands. This mode is useful when CRP is required and flash field updates are needed but all sectors can not be erased.
- CRP2 disables access to the chip via the SWD and only allows full flash erase and update using a reduced set of the ISP commands.
- 3. Running an application with level CRP3 selected fully disables any access to the chip via the SWD pins and the ISP. This mode effectively disables ISP override using PIO0\_1 pin, too. It is up to the user's application to provide (if needed) flash update mechanism using IAP calls or call reinvoke ISP command to enable flash update via the UART.

#### CAUTION



If level three Code Read Protection (CRP3) is selected, no future factory testing can be performed on the device.

In addition to the three CRP levels, sampling of pin PIO0\_1 for valid user code can be disabled. For details see the *LPC112x user manual*.

#### 7.16.5 APB interface

The APB peripherals are located on one APB bus.

#### 7.16.6 AHBLite

The AHBLite connects the CPU bus of the ARM Cortex-M0 to the flash memory, the main static RAM, and the Boot ROM.

#### 7.16.7 External interrupt inputs

All GPIO pins can be level or edge sensitive interrupt inputs. In addition, start logic inputs serve as external interrupts (see <u>Section 7.16.1</u>).

#### 7.17 Emulation and debugging

Debug functions are integrated into the ARM Cortex-M0. Serial wire debug with four breakpoints and two watchpoints is supported.

## 8. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).[1]

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DD</sub>	supply voltage (core and external rail)		[2]	-0.5	+4.6	V
V <sub>DDA</sub>	analog supply voltage		[2]	-0.5	+4.6	V
V <sub>ref</sub>	reference voltage	on pin VREFP		-0.5	+4.6	V
Vı	input voltage	5 V tolerant I/O pins; only valid when the V <sub>DD</sub> supply voltage is present	[5][2]	-0.5	+5.5	V
		5 V tolerant open-drain pins PIO0_4 and PIO0_5	[2][4]	-0.5	+5.5	V
V <sub>IA</sub>	analog input voltage	pin configured as analog input	[2] [3]	-0.5	4.6	V
I <sub>DD</sub>	supply current	per supply pin		-	100	mA
I <sub>SS</sub>	ground current	per ground pin		-	100	mA
I <sub>latch</sub>	I/O latch-up current	-(0.5V <sub>DD</sub> ) < V <sub>I</sub> < (1.5V <sub>DD</sub> ); T <sub>j</sub> < 125 °C		-	100	mA
T <sub>stg</sub>	storage temperature	non-operating	<u>[6]</u>	-65	+150	°C
T <sub>j(max)</sub>	maximum junction temperature			-	150	°C
P <sub>tot(pack)</sub>	total power dissipation (per package)	based on package heat transfer, not device power consumption		-	1.5	W
V <sub>ESD</sub>	electrostatic discharge voltage	human body model; all pins	[7]		+6500	V

[1] The following applies to the limiting values:

a) This product includes circuitry specifically designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying greater than the rated maximum.

b) Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V<sub>SS</sub> unless otherwise noted.

- c) The limiting values are stress ratings only. Operating the part at these values is not recommended, and proper operation is not guaranteed. The conditions for functional operation are specified in <u>Table 6</u>.
- [2] Maximum/minimum voltage above the maximum operating voltage (see <u>Table 6</u>) and below ground that can be applied for a short time (< 10 ms) to a device without leading to irrecoverable failure. Failure includes the loss of reliability and shorter lifetime of the device.
- [3] See <u>Table 6</u> for maximum operating voltage.
- [4] V<sub>DD</sub> present or not present. Compliant with the I<sup>2</sup>C-bus standard. 5.5 V can be applied to this pin when V<sub>DD</sub> is powered down.
- [5] Including voltage on outputs in 3-state mode.
- [6] The maximum non-operating storage temperature is different than the temperature for required shelf life which should be determined based on required shelf lifetime. Please refer to the JEDEC spec (J-STD-033B.1) for further details.
- [7] Human body model: equivalent to discharging a 100 pF capacitor through a 1.5 k $\Omega$  series resistor.

## 9. Thermal characteristics

The average chip junction temperature,  $T_{j}\,(^{\circ}C),$  can be calculated using the following equation:

$$T_j = T_{amb} + (P_D \times R_{th(j-a)}) \tag{1}$$

- T<sub>amb</sub> = ambient temperature (°C)
- R<sub>th(j-a)</sub> = the package junction-to-ambient thermal resistance (°C/W)
- P<sub>D</sub> = sum of internal and I/O power dissipation

The internal power dissipation is the product of  $I_{DD}$  and  $V_{DD}$ . The I/O power dissipation of the I/O pins is often small and many times can be negligible. However it can be significant in some applications.

#### Table 5.Thermal resistance value (C/W): ±15 %

LQFP48	
θја	
JEDEC (4.5 in × 4 in)	
0 m/s	82.1
1 m/s	73.7
2.5 m/s	68.2
8-layer (4.5 in × 3 in)	
0 m/s	115.2
1 m/s	94.7
2.5 m/s	86.3
θјс	29.6
θjb	34.2

## **10. Static characteristics**

#### Table 6. Static characteristics

 $T_{amb} = -40$  °C to +105 °C, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ <mark>[1]</mark>	Max	Unit
V <sub>DD</sub>	supply voltage (core and external rail)			1.8	3.3	3.6	V
V <sub>DDA</sub>	analog supply voltage			2.4	3.3	3.6	V
V <sub>ref</sub>	reference voltage	on pin VREFP		2.4	-	V <sub>DDA</sub>	V
Power cons	umption in low-current mo	ode[11]					
I <sub>DD</sub>	supply current	Active mode; code					
		while(1){}					
		executed from flash					
		system clock = 1 MHz	[2][3][5][6][7]	-	0.7	-	mA
		V <sub>DD</sub> = 3.3 V					
		system clock = 6 MHz	[2][3][5]	-	1.0	-	mA
		V <sub>DD</sub> = 3.3 V	<u>[6][7]</u>				
		system clock = 12 MHz	[2][3][4]	-	1.5	-	mA
		V <sub>DD</sub> = 3.3 V	<u>[6][7]</u>				
		system clock = 50 MHz	[2][3][6]	-	6.0	-	mA
		V <sub>DD</sub> = 3.3 V	<u>[7][8]</u>				
		Sleep mode;	[2][3][4]	-	0.8	-	mA
		system clock = 12 MHz	<u>[6][7]</u>				
		V <sub>DD</sub> = 3.3 V					
		system clock = 50 MHz	[2][3][4]	-	2.4	-	mA
		V <sub>DD</sub> = 3.3 V	<u>[6][7]</u>				
I <sub>DD</sub>	supply current	Deep-sleep mode; V <sub>DD</sub> = 3.3 V;	<u>[2][3][9]</u>				
		T <sub>amb</sub> = 25 °C		-	1.8	8	μA
		T <sub>amb</sub> = 105 °C		-	-	65	μA
I <sub>DD</sub>	supply current	Deep power-down mode; $V_{DD} = 3.3 V$ ;	[2][10]				
		T <sub>amb</sub> = 25 °C		-	220	900	nA
		T <sub>amb</sub> = 105 °C		-	-	3.5	μA
Standard po	rt pins, RESET						
IIL	LOW-level input current	$V_I = 0 V$ ; on-chip pull-up resistor disabled		-	0.5	10[17]	nA
I <sub>IH</sub>	HIGH-level input current	V <sub>I</sub> = V <sub>DD</sub> ; on-chip pull-down resistor disabled		-	0.5	10 <sup>[17]</sup>	nA
I <sub>OZ</sub>	OFF-state output current	$V_O = 0 V$ ; $V_O = V_{DD}$ ; on-chip pull-up/down resistors disabled		-	0.5	10 <u><sup>[17]</sup></u>	nA
VI	input voltage	pin configured to provide a digital function; $V_{DD} \ge 1.8 \text{ V}$	[12] [14]	0	-	5.0	V

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
		$V_{DD} = 0 V$		0	-	3.6	V
Vo	output voltage	output active		0	-	V <sub>DD</sub>	V
V <sub>IH</sub>	HIGH-level input voltage			0.7 V <sub>DD</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	0.3V <sub>DD</sub>	V
V <sub>hys</sub>	hysteresis voltage			-	0.4	-	V
V <sub>OH</sub>	HIGH-level output voltage	$\begin{array}{l} 2.5 \ \text{V} \leq \text{V}_{\text{DD}} \leq 3.6 \ \text{V}; \\ \text{I}_{\text{OH}} = -4 \ \text{mA} \end{array}$		$V_{DD} - 0.4$	-	-	V
		$\begin{array}{l} 1.8 \ V \leq V_{DD} < 2.5 \ V; \\ I_{OH} = -3 \ mA \end{array}$		V <sub>DD</sub> - 0.4	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$\begin{array}{l} 2.5 \ \text{V} \leq \text{V}_{\text{DD}} \leq 3.6 \ \text{V}; \\ \text{I}_{\text{OL}} = 4 \ \text{mA} \end{array}$		-	-	0.4	V
		$\begin{array}{l} 1.8 \ V \leq V_{DD} < 2.5 \ V; \\ I_{OL} = 3 \ mA \end{array} \label{eq:VDD}$		-	-	0.4	V
l <sub>ОН</sub>	HIGH-level output current	$V_{OH} = V_{DD} - 0.4 V;$ 1.8 V $\leq V_{DD} \leq 3.6 V$		-3	-	-	mA
OL	LOW-level output current	$V_{OL} = 0.4 V$ 1.8 V $\leq V_{DD} \leq 3.6 V$		3	-	-	mA
I <sub>OHS</sub>	HIGH-level short-circuit output current	V <sub>OH</sub> = 0 V	[15]	-	-	-45	mA
I <sub>OLS</sub>	LOW-level short-circuit output current	$V_{OL} = V_{DD}$	[15]	-	-	50	mA
I <sub>pd</sub>	pull-down current	V <sub>1</sub> = 5 V		10	50	150	μA
pu	pull-up current	$V_{I} = 0 V;$ 2.0 V $\leq V_{DD} \leq 3.6 V$		-15	-50	-85	μA
		$1.8 \text{ V} \le \text{V}_{\text{DD}} < 2.0 \text{ V}$		-10	-50	-85	μA
		V <sub>DD</sub> < V <sub>I</sub> < 5 V		0	0	0	μA
High-drive o	output pin (PIO0_7)						
lıL	LOW-level input current	$V_I = 0 V$ ; on-chip pull-up resistor disabled		-	0.5	10[17]	nA
IH	HIGH-level input current	V <sub>I</sub> = V <sub>DD</sub> ; on-chip pull-down resistor disabled		-	0.5	10[17]	nA
oz	OFF-state output current	$V_O = 0 V; V_O = V_{DD};$ on-chip pull-up/down resistors disabled		-	0.5	10 <sup>[17]</sup>	nA
VI	input voltage	pin configured to provide a digital function; $V_{DD} \ge 1.8 \text{ V}$	<u>[12]</u> [14]	0	-	5.0	V
		$V_{DD} = 0 V$		0	-	3.6	V
Vo	output voltage	output active		0	-	V <sub>DD</sub>	V

#### Table 6. Static characteristics ... continued

Symbol	Parameter	Conditions		Min	Typ <mark>[1]</mark>	Max	Unit
V <sub>IH</sub>	HIGH-level input voltage			0.7V <sub>DD</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	$0.3V_{DD}$	V
V <sub>hys</sub>	hysteresis voltage			0.4	-	-	V
V <sub>OH</sub>	HIGH-level output voltage	$\begin{array}{l} 2.5 \ V \leq V_{DD} \leq 3.6 \ V; \\ I_{OH} = -20 \ mA \end{array} \label{eq:VDD}$		$V_{DD} - 0.5$	-	-	V
		$\begin{array}{l} 1.8 \ V \leq V_{DD} < 2.5 \ V; \\ I_{OH} = -12 \ mA \end{array} \label{eq:VDD}$		$V_{DD} - 0.5$	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$\begin{array}{l} 2.5 \ V \leq V_{DD} \leq 3.6 \ V; \\ I_{OL} = 4 \ mA \end{array} \label{eq:VDD}$		-	-	0.4	V
		$\begin{array}{l} 1.8 \ \text{V} \leq \text{V}_{\text{DD}} < 2.5 \ \text{V}; \\ \text{I}_{\text{OL}} = 3 \ \text{mA} \end{array}$		-	-	0.4	V
I <sub>ОН</sub>	HIGH-level output current			20	-	-	mA
		$1.8~V \leq V_{DD} < 2.5~V$		12	-	-	mA
I <sub>OL</sub>	LOW-level output current	$V_{OL} = 0.4 V$ 2.5 V $\leq V_{DD} \leq 3.6 V$		4	-	-	mA
		$1.8~\text{V} \leq \text{V}_{\text{DD}} < 2.5~\text{V}$		3	-	-	mA
I <sub>OLS</sub>	LOW-level short-circuit output current	V <sub>OL</sub> = V <sub>DD</sub>	<u>[15]</u>	-	-	50	mA
I <sub>pd</sub>	pull-down current	V <sub>I</sub> = 5 V		10	50	150	μA
I <sub>pu</sub>	pull-up current	$V_{I} = 0 V$ 2.0 V $\leq V_{DD} \leq 3.6 V$		–15	-50	-85	μA
		$1.8 \text{ V} \le \text{V}_{\text{DD}}$ < 2.0 V		-10	-50	-85	μA
		V <sub>DD</sub> < V <sub>I</sub> < 5 V		0	0	0	μA
I <sup>2</sup> C-bus pins	s (PIO0_4 and PIO0_5)						
V <sub>IH</sub>	HIGH-level input voltage			0.7V <sub>DD</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	$0.3V_{DD}$	V
V <sub>hys</sub>	hysteresis voltage			-	$0.05V_{DD}$	-	V
I <sub>OL</sub>	LOW-level output current	$\label{eq:Vol} \begin{array}{l} V_{OL} = 0.4 \mbox{ V; } l^2C\mbox{-bus pins} \\ \mbox{configured as standard} \\ \mbox{mode pins} \\ \mbox{2.5 V} \leq V_{DD} \leq 3.6 \mbox{ V} \end{array}$		3.5	-	-	mA
		$1.8~\text{V} \leq \text{V}_{\text{DD}} < 2.5~\text{V}$		3	-	-	
I <sub>OL</sub>	LOW-level output current	$\label{eq:Vol} \begin{array}{l} V_{OL} = 0.4 \text{ V}; \ l^2C\text{-bus pins} \\ \text{configured as Fast-mode} \\ \text{Plus pins} \\ 2.5 \text{ V} \leq V_{DD} \leq 3.6 \text{ V} \end{array}$		20	-	-	mA
		$1.8 \text{ V} \le \text{V}_{\text{DD}}$ < 2.5 V		16	-	-	

## Table 6.Static characteristics ...continued $T_{amb} = -40$ °C to +105 °C, unless otherwise specified.

## Table 6. Static characteristics ...continued

 $T_{amb} = -40$  °C to +105 °C, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ <mark>[1]</mark>	Max	Unit
ILI	input leakage current	$V_I = V_{DD}$	[16]	-	2	4	μA
		V <sub>I</sub> = 5 V		-	10	22	μA
Oscillator pins	5						
V <sub>i(xtal)</sub>	crystal input voltage			-0.5	1.8	1.95	V
V <sub>o(xtal)</sub>	crystal output voltage			-0.5	1.8	1.95	V

#### 32-bit ARM Cortex-M0 microcontroller

$I_{amb} = -40$ °C to +105 °C, unless otherwise specified.						
Symbol	Parameter	Conditions	Min	Typ <mark>[1]</mark>	Max	Unit
Pin capacit	ance		i			!
C <sub>io</sub>	input/output capacitance	pins configured for analog function	-	-	7.1	pF
		I <sup>2</sup> C-bus pins (PIO0_4 and PIO0_5)	-	-	2.5	pF
		pins configured as GPIO	-	-	2.8	pF

#### Table 6. Static characteristics ...continued

.....

[1] Typical ratings are not guaranteed. The values listed are at room temperature (25 °C), nominal supply voltages.

[2]  $T_{amb} = 25 \ ^{\circ}C.$ 

[3] I<sub>DD</sub> measurements were performed with all pins configured as GPIO outputs driven LOW and pull-up resistors disabled.

[4] IRC enabled; system oscillator disabled; system PLL disabled.

[5] System oscillator enabled; IRC disabled; system PLL disabled.

[6] BOD disabled.

- All peripherals disabled in the SYSAHBCLKCTRL register. Peripheral clocks to UART and SSP0/1 disabled in system configuration [7] block.
- [8] IRC disabled; system oscillator enabled; system PLL enabled.
- [9] All oscillators and analog blocks turned off in the PDSLEEPCFG register; PDSLEEPCFG = 0x0000 18FF.
- [10] WAKEUP pin pulled HIGH externally.
- [11] Low-current mode PWR\_LOW\_CURRENT selected when running the set\_power routine in the power profiles.
- [12] Including voltage on outputs in 3-state mode.
- [13] V<sub>DD</sub> supply voltage must be present.
- [14] 3-state outputs go into 3-state mode in Deep power-down mode.
- [15] Allowed as long as the current limit does not exceed the maximum current allowed by the device.

[16] To V<sub>SS</sub>.

[17] Characterized on samples. Not tested in production.

#### **10.1 Power consumption**

Power measurements in Active, Sleep, and Deep-sleep modes were performed under the following conditions (see *LPC112x user manual*):

- Configure all pins as GPIO with pull-up resistor disabled in the IOCON block.
- Configure GPIO pins as outputs using the GPIOnDIR registers.
- Write 0 to all GPIOnDATA registers to drive the outputs LOW.



#### 32-bit ARM Cortex-M0 microcontroller



#### 32-bit ARM Cortex-M0 microcontroller







## 10.2 CoreMark data

Remark: All CoreMark data were taken with the Keil uVision v. 5.1.0 tool.

#### 32-bit ARM Cortex-M0 microcontroller



### 10.3 Peripheral power consumption

The supply current per peripheral is measured as the difference in supply current between the peripheral block enabled and the peripheral block disabled in the SYSAHBCLKCFG and PDRUNCFG (for analog blocks) registers. All other blocks are disabled in both registers and no code is executed. Measured on a typical sample at  $T_{amb} = 25$  °C. Unless noted otherwise, the system oscillator and PLL are running in both measurements.

The supply currents are shown for system clock frequencies of 12 MHz and 48 MHz.

Peripheral	Typical supply current in mA		rrent in	Notes		
	n/a	12 MHz	48 MHz			
IRC	0.212	-	-	System oscillator running; PLL off; independent of main clock frequency.		
System oscillator at 12 MHz	0.1928	-	-	IRC running; PLL off; independent of main clock frequency.		
Watchdog oscillator at 500 kHz/2	0.002	-	-	System oscillator running; PLL off; independent of main clock frequency.		
BOD	0.051	-	-	Independent of main clock frequency.		
Main PLL	-	0.0686	-			
ADC	-	0.0532	0.2074			
CLKOUT	-	0.0104	0.0392	Main clock divided by 4 in the CLKOUTDIV register.		
CT16B0	-	0.0266	0.1028			
CT16B1	-	0.025	0.0956			
CT32B0	-	0.026	0.0998			
CT32B1	-	0.0246	0.0956			
GPIO	-	0.2252	0.8754	GPIO pins configured as outputs and set to LOW. Direction and pin state are maintained if the GPIO is disabled in the SYSAHBCLKCFG register.		
IOCON	-	0.0324	0.1262			
I2C	-	0.0384	0.1484			
ROM	-	0.017	0.0658			
SSP0	-	0.0482	0.187			
SSP1	-	0.048	0.1862			
UART0	-	0.0862	0.334			
UART1	-	0.0836	0.3236			
UART2	-	0.0818	0.3176			
WWDT	-	0.039	0.1964	Main clock selected as clock source for the WDT.		

 Table 7.
 Power consumption for individual analog and digital blocks

**LPC112x** 



## **10.4 Electrical pin characteristics**



# LPC112x

aaa-013976

0.5 V<sub>OL</sub> (V) 0.6

#### 32-bit ARM Cortex-M0 microcontroller



Conditions:  $V_{DD}$  = 1.8 V; standard port pins and high-drive pin PIO0\_7.

Conditions:  $V_{DD}$  = 3.3 V; standard port pins and high-drive pin PIO0\_7.

Fig 13. Typical LOW-level output current I<sub>OL</sub> versus LOW-level output voltage V<sub>OL</sub>


### 32-bit ARM Cortex-M0 microcontroller



Conditions:  $V_{DD}$  = 1.8 V; standard port pins.





Fig 16. Typical pull-down current  $I_{PD}$  versus input voltage  $V_I$ 



Conditions:  $V_{DD}$  = 3.3 V; standard port pins.



# **11. Dynamic characteristics**

# 11.1 Flash memory

#### Table 8. Flash characteristics

 $T_{amb} = -40 \ ^{\circ}C$  to +105  $^{\circ}C$ , unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
N <sub>endu</sub>	endurance		<u>[1]</u>	10000	100000	-	cycles
t <sub>ret</sub>	retention time	powered		10	-	-	years
		unpowered		20	-	-	years
t <sub>er</sub>	erase time	sector or multiple consecutive sectors		95	100	105	ms
t <sub>prog</sub>	programming time		[2]	0.95	1	1.05	ms

[1] Number of program/erase cycles.

[2] Programming times are given for writing 256 bytes from RAM to the flash. Data must be written to the flash in blocks of 256 bytes.

# 11.2 External clock

#### Table 9. Dynamic characteristic: external clock

 $T_{amb} = -40$  °C to +105 °C;  $V_{DD}$  over specified ranges.<sup>[1]</sup>

Symbol	Parameter	Min	Typ <sup>[2]</sup>	Max	Unit
f <sub>osc</sub>	oscillator frequency	1	-	25	MHz
T <sub>cy(clk)</sub>	clock cycle time	40	-	1000	ns
t <sub>CHCX</sub>	clock HIGH time	$T_{cy(clk)}\times 0.4$	-	-	ns
t <sub>CLCX</sub>	clock LOW time	$T_{cy(clk)}\times 0.4$	-	-	ns
t <sub>CLCH</sub>	clock rise time	-	-	5	ns
t <sub>CHCL</sub>	clock fall time	-	-	5	ns

[1] Parameters are valid over operating temperature range unless otherwise specified.

[2] Typical ratings are not guaranteed. The values listed are at room temperature (25 °C), nominal supply voltages.



# 11.3 Internal oscillators

#### Table 10. Dynamic characteristics: IRC

 $T_{amb} = -40 \text{ °C to } +105 \text{ °C}; 2.7 \text{ V} \le V_{DD} \le 3.6 \text{ V}^{[1]}.$ 

unio		55				
Symbol	Parameter	Conditions	Min	Typ <mark>[2]</mark>	Max	Unit
f <sub>osc(RC)</sub>	internal RC oscilla-	$-25~^\circ C \leq T_{amb} \leq +85~^\circ C$	12 - 1 %	12	12 + 1 %	MHz
	tor frequency	$-40 \text{ °C} \le T_{amb} < -25 \text{ °C}$	12 - 2.5 %	12	12 + 1 %	MHz
		$85 \text{ °C} < T_{amb} \le 105 \text{ °C}$	12 - 1.5 %	12	12 + 1.5 %	MHz

[1] Parameters are valid over operating temperature range unless otherwise specified.

[2] Typical ratings are not guaranteed. The values listed are for room temperature (25 °C), nominal supply voltages.





#### Table 11. Dynamic characteristics: WatchDog oscillator

Symbol	Parameter	Conditions		Min	Typ <mark>[1]</mark>	Мах	Unit
f <sub>osc(int)</sub>	internal oscillator frequency	DIVSEL = 0x1F, FREQSEL = 0x1 in the WDTOSCCTRL register;	[2][3]	-	9.4	-	kHz
		DIVSEL = 0x00, FREQSEL = 0xF in the WDTOSCCTRL register	[2][3]	-	2300	-	kHz

[1] Typical ratings are not guaranteed. The values listed are at nominal supply voltages.

[2] The typical frequency spread over processing and temperature (T<sub>amb</sub> = -40 °C to +105 °C) is  $\pm$ 40 %.

[3] See the LPC112x user manual.

### 32-bit ARM Cortex-M0 microcontroller

# 11.4 I/O pins

#### Table 12. Dynamic characteristic: I/O pins<sup>[1]</sup>

 $T_{amb} = -40$  °C to +105 °C; 3.0 V  $\leq V_{DD} \leq 3.6$  V.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>r</sub>	rise time	pin configured as output	3.0	-	5.0	ns
t <sub>f</sub>	fall time	pin configured as output	2.5	-	5.0	ns

[1] Applies to standard port pins and RESET pin.

32-bit ARM Cortex-M0 microcontroller

# 11.5 I<sup>2</sup>C-bus

#### Table 13. Dynamic characteristic: I<sup>2</sup>C-bus pins<sup>[1]</sup>

$T_{amb} = -40$	0 ℃ t	o +105	°C.[2]
-----------------	-------	--------	--------

Symbol	Parameter		Conditions	Min	Max	Unit
f <sub>SCL</sub>	SCL clock		Standard-mode	0	100	kHz
	frequency		Fast-mode	0	400	kHz
			Fast-mode Plus	0	1	MHz
t <sub>f</sub>	fall time	<u>[4][5][6][7]</u>	of both SDA and SCL signals	-	300	ns
			Standard-mode			
			Fast-mode	$20 + 0.1 \times C_b$	300	ns
			Fast-mode Plus	-	120	ns
t <sub>LOW</sub>	LOW period of		Standard-mode	4.7	-	μs
	the SCL clock		Fast-mode	1.3	-	μs
			Fast-mode Plus	0.5	-	μs
t <sub>HIGH</sub>	HIGH period of		Standard-mode	4.0	-	μs
	the SCL clock		Fast-mode	0.6	-	μs
			Fast-mode Plus	0.26	-	μs
t <sub>HD;DAT</sub>	data hold time	<u>[3][4][8]</u>	Standard-mode	0	-	μs
			Fast-mode	0	-	μs
			Fast-mode Plus	0	-	μs
t <sub>SU;DAT</sub>	data set-up	<u>[9][10]</u>	Standard-mode	250	-	ns
	time		Fast-mode	100	-	ns
			Fast-mode Plus	50	-	ns

[1] See the I<sup>2</sup>C-bus specification UM10204 for details.

[2] Parameters are valid over operating temperature range unless otherwise specified.

- [3] t<sub>HD;DAT</sub> is the data hold time that is measured from the falling edge of SCL; applies to data in transmission and the acknowledge.
- [4] A device must internally provide a hold time of at least 300 ns for the SDA signal (with respect to the  $V_{IH}(min)$  of the SCL signal) to bridge the undefined region of the falling edge of SCL.
- [5]  $C_b$  = total capacitance of one bus line in pF.
- [6] The maximum t<sub>f</sub> for the SDA and SCL bus lines is specified at 300 ns. The maximum fall time for the SDA output stage t<sub>f</sub> is specified at 250 ns. This allows series protection resistors to be connected in between the SDA and the SCL pins and the SDA/SCL bus lines without exceeding the maximum specified t<sub>f</sub>.
- [7] In Fast-mode Plus, fall time is specified the same for both output stage and bus timing. If series resistors are used, designers should allow for this when considering bus timing.
- [8] The maximum t<sub>HD;DAT</sub> could be 3.45 μs and 0.9 μs for Standard-mode and Fast-mode but must be less than the maximum of t<sub>VD;DAT</sub> or t<sub>VD;ACK</sub> by a transition time (see *UM10204*). This maximum must only be met if the device does not stretch the LOW period (t<sub>LOW</sub>) of the SCL signal. If the clock stretches the SCL, the data must be valid by the set-up time before it releases the clock.
- [9] t<sub>SU;DAT</sub> is the data set-up time that is measured with respect to the rising edge of SCL; applies to data in transmission and the acknowledge.
- [10] A Fast-mode I<sup>2</sup>C-bus device can be used in a Standard-mode I<sup>2</sup>C-bus system but the requirement t<sub>SU;DAT</sub> = 250 ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line t<sub>r(max)</sub> + t<sub>SU;DAT</sub> = 1000 + 250 = 1250 ns (according to the Standard-mode I<sup>2</sup>C-bus specification) before the SCL line is released. Also the acknowledge timing must meet this set-up time.

LPC112x

© NXP Semiconductors N.V. 2015. All rights reserved.

# LPC112x

### 32-bit ARM Cortex-M0 microcontroller



# **11.6 SSP interfaces**

Table 14.	Dynamic characteristics of SSP pins in SPI mode	
-----------	---	--

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
SSP mast	ter (in SPI mode)						
T <sub>cy(clk)</sub>	clock cycle time	full-duplex mode	<u>[1]</u>	50	-	-	ns
		when only transmitting	<u>[1]</u>	40			ns
t <sub>DS</sub>	data set-up time	in SPI mode	[2]	20	-	-	ns
		$2.4~V \leq V_{DD} \leq 3.6~V$					
		$2.0~\textrm{V} \leq \textrm{V}_\textrm{DD} < 2.4~\textrm{V}$	[2]	25			ns
		$1.8 \text{ V} \le \text{V}_{\text{DD}}$ < 2.0 V	[2]	29	-	-	ns
t <sub>DH</sub>	data hold time	in SPI mode	[2]	0	-	-	ns
t <sub>v(Q)</sub>	data output valid time	in SPI mode	[2]	-	-	10	ns
t <sub>h(Q)</sub>	data output hold time	in SPI mode	[2]	0	-	-	ns
	e (in SPI mode)						
T <sub>cy(PCLK)</sub>	PCLK cycle time			20	-	-	ns
t <sub>DS</sub>	data set-up time	in SPI mode	<u>[3][4]</u>	0	-	-	ns
t <sub>DH</sub>	data hold time	in SPI mode	<u>[3][4]</u>	$3 \times T_{cy(PCLK)} + 4$	-	-	ns
t <sub>v(Q)</sub>	data output valid time	in SPI mode	<u>[3][4]</u>	-	-	$3 \times T_{cy(PCLK)}$ + 11	ns
t <sub>h(Q)</sub>	data output hold time	in SPI mode	[3][4]	-	-	$2 \times T_{cy(PCLK)} + 5$	ns

[1]  $T_{cy(clk)} = (SSPCLKDIV \times (1 + SCR) \times CPSDVSR) / f_{main}$ . The clock cycle time derived from the SSP bit rate  $T_{cy(clk)}$  is a function of the main clock frequency  $f_{main}$ , the SSP peripheral clock divider (SSPCLKDIV), the SSP SCR parameter (specified in the SSP0CR0 register), and the SSP CPSDVSR parameter (specified in the SSP clock prescale register).

[2]  $T_{amb} = -40 \text{ °C to } 105 \text{ °C}.$ 

[3]  $T_{cy(clk)} = 12 \times T_{cy(PCLK)}$ .

[4]  $T_{amb} = 25 \text{ °C}$ ; for normal voltage supply range:  $V_{DD} = 3.3 \text{ V}$ .

### 32-bit ARM Cortex-M0 microcontroller



# LPC112x

### 32-bit ARM Cortex-M0 microcontroller



LPC112x

# 12. Analog characteristics

## 12.1 BOD static characteristics

### Table 15. BOD static characteristics<sup>[1]</sup>

 $T_{amb} = 25 \ ^{\circ}C.$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>th</sub>	threshold voltage	interrupt level 1				
		assertion	-	2.22	-	V
		de-assertion	-	2.35	-	V
		interrupt level 2				
		assertion	-	2.52	-	V
		de-assertion	-	2.66	-	V
		interrupt level 3				
		assertion	-	2.80	-	V
		de-assertion	-	2.90	-	V
		reset level 0				
		assertion	-	1.46	-	V
		de-assertion	-	1.63	-	V
		reset level 1				
		assertion	-	2.06	-	V
		de-assertion	-	2.15	-	V
		reset level 2				
		assertion	-	2.35	-	V
	de-assertion	-	2.43	-	V	
		reset level 3				
		assertion	-	2.63	-	V
		de-assertion	-	2.71	-	V

[1] Interrupt levels are selected by writing the level value to the BOD control register BODCTRL, see *LPC111x* user manual.

# 12.2 12-bit ADC

#### Table 16. 12-bit ADC static characteristics

 $T_{amb} = -40$  °C to +105 °C;  $V_{DD} = 2.4$  V to 3.6 V; VREFP =  $V_{DDA}$ ;  $V_{SSA} = 0$ ; VREFN =  $V_{SSA}$ .

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>IA</sub>	analog input voltage		<u>[1]</u>	0		V <sub>DDA</sub>	V
C <sub>ia</sub>	analog input capacitance			-		2.5	pF
f <sub>clk(ADC)</sub>	ADC clock frequency	$V_{DDA} \ge 2.7 \text{ V}$	[8]			50	MHz
		$V_{DDA} \ge 2.4 \text{ V}$	[9]			25	MHz
f <sub>s</sub>	sampling frequency	$V_{DDA} \ge 2.7 \text{ V}$	[8]	-		2	Msamples/s
		$V_{DDA} \ge 2.4 \text{ V}$	[9]	-		1	Msamples/s
E <sub>D</sub>	differential linearity error		[2]	-	+/- 2	-	LSB
E <sub>L(adj)</sub>	integral non-linearity		[3]	-	+/- 2	-	LSB
Eo	offset error		[4]	-	+/- 3	-	LSB
V <sub>err(fs)</sub>	full-scale error voltage	2 Msamples/s	[5]	-	+/- 0.12	-	%
		1 Msamples/s			+/- 0.07	-	%
Zi	input impedance	f <sub>s</sub> = 2 Msamples/s	<u>[6][7]</u>	0.1		-	MΩ

- [1] The input resistance of ADC channel 0 is higher than for all other channels.
- [2] The differential linearity error (E<sub>D</sub>) is the difference between the actual step width and the ideal step width. See Figure 22.
- [3] The integral non-linearity (E<sub>L(adj)</sub>) is the peak difference between the center of the steps of the actual and the ideal transfer curve after appropriate adjustment of gain and offset errors. See <u>Figure 22</u>.
- [4] The offset error ( $E_0$ ) is the absolute difference between the straight line which fits the actual curve and the straight line which fits the ideal curve. See Figure 22.
- [5] The full-scale error voltage or gain error (E<sub>G</sub>) is the difference between the straight line fitting the actual transfer curve after removing offset error, and the straight line which fits the ideal transfer curve. See <u>Figure 22</u>.
- [6]  $T_{amb} = 25 \text{ °C}$ ; maximum sampling frequency  $f_s = 2$  Msamples/s and analog input capacitance  $C_{ia} = 0.32 \text{ pF}$ .
- [7] Input impedance  $Z_i$  is inversely proportional to the sampling frequency and the total input capacity including  $C_{ia}$  and  $C_{io}$ :  $Z_i \propto 1 / (f_s \times C_i)$ . See <u>Table 6</u> for  $C_{io}$ .
- [8] In the ADC TRM register, set VRANGE = 0 (default).
- [9] In the ADC TRM register, set VRANGE = 1.

# LPC112x

### 32-bit ARM Cortex-M0 microcontroller



LPC112x

# 32-bit ARM Cortex-M0 microcontroller



# **13. Application information**

# 13.1 ADC usage notes

The following guidelines show how to increase the performance of the ADC in a noisy environment beyond the ADC specifications listed in <u>Table 6</u>:

- The ADC input trace must be short and as close as possible to the LPC112x chip.
- The ADC input traces must be shielded from fast switching digital signals and noisy power supply lines.
- Because the ADC and the digital core share the same power supply, the power supply line must be adequately filtered.
- To improve the ADC performance in a very noisy environment, put the device in Sleep mode during the ADC conversion.

## 13.2 XTAL input

The input voltage to the on-chip oscillators is limited to 1.8 V. If the oscillator is driven by a clock in slave mode, it is recommended that the input be coupled through a capacitor with  $C_i = 100 \text{ pF}$ . To limit the input voltage to the specified range, choose an additional capacitor to ground  $C_g$  which attenuates the input voltage by a factor  $C_i/(C_i + C_g)$ . In slave mode, a minimum of 200 mV (RMS) is needed.



In slave mode the input clock signal should be coupled by means of a capacitor of 100 pF (Figure 24), with an amplitude between 200 mV (RMS) and 1000 mV (RMS). This corresponds to a square wave signal with a signal swing of between 280 mV and 1.4 V. The XTALOUT pin in this configuration can be left unconnected.

External components and models used in oscillation mode are shown in Figure 25 and in Table 17 and Table 18. Since the feedback resistance is integrated on chip, only a crystal and the capacitances  $C_{X1}$  and  $C_{X2}$  need to be connected externally in case of fundamental mode oscillation (the fundamental frequency is represented by L,  $C_L$  and  $R_S$ ). Capacitance  $C_P$  in Figure 25 represents the parallel package capacitance and should not be larger than 7 pF. Parameters  $F_{OSC}$ ,  $C_L$ ,  $R_S$  and  $C_P$  are supplied by the crystal manufacturer (see Table 17).

### 32-bit ARM Cortex-M0 microcontroller



Table 17.	Recommended values for $C_{X1}/C_{X2}$ in oscillation mode (crystal and external
	components parameters) low frequency mode

Fundamental oscillation frequency F <sub>OSC</sub>	Crystal load capacitance C <sub>L</sub>	Maximum crystal series resistance R <sub>S</sub>	External load capacitors C <sub>X1</sub> , C <sub>X2</sub>
1 MHz to 5 MHz	10 pF	< 300 Ω	18 pF, 18 pF
	20 pF	< 300 Ω	39 pF, 39 pF
	30 pF	< 300 Ω	57 pF, 57 pF
5 MHz to 10 MHz	10 pF	< 300 Ω	18 pF, 18 pF
	20 pF	< 200 Ω	39 pF, 39 pF
	30 pF	< 100 Ω	57 pF, 57 pF
10 MHz to 15 MHz	10 pF	< 160 Ω	18 pF, 18 pF
	20 pF	< 60 Ω	39 pF, 39 pF
15 MHz to 20 MHz	10 pF	< 80 Ω	18 pF, 18 pF

Table 18. Recommended values for  $C_{X1}/C_{X2}$  in oscillation mode (crystal and external components parameters) high frequency mode

		Maximum crystal series resistance R <sub>S</sub>	External load capacitors C <sub>X1</sub> , C <sub>X2</sub>	
15 MHz to 20 MHz	10 pF	< 180 Ω	18 pF, 18 pF	
	20 pF	< 100 Ω	39 pF, 39 pF	
20 MHz to 25 MHz	10 pF	< 160 Ω	18 pF, 18 pF	
	20 pF	< 80 Ω	39 pF, 39 pF	

# 13.3 XTAL Printed Circuit Board (PCB) layout guidelines

The crystal should be connected on the PCB as close as possible to the oscillator input and output pins of the chip. Take care that the load capacitors  $C_{X1}$ ,  $C_{X2}$ , and  $C_{X3}$  in case of third overtone crystal usage have a common ground plane. The external components must also be connected to the ground plain. Loops must be made as small as possible in

order to keep the noise coupled in via the PCB as small as possible. Also parasitics should stay as small as possible. Values of  $C_{X1}$  and  $C_{X2}$  should be chosen smaller accordingly to the increase in parasitics of the PCB layout.

# 13.4 Connecting power, clocks, and debug functions

Figure 26 shows the basic board connections used to power the LPC112x and provide debug capabilities via the serial wire port.

# LPC112x

### 32-bit ARM Cortex-M0 microcontroller



(5) When measuring signals of low frequency, use a low-pass filter to remove noise and to improve ADC performance. Also see <u>Ref. 4</u>.

Fig 26. Power, clock, and debug connections

# 13.5 Termination of unused pins

Table 19 shows how to terminate pins that are **not** used in the application. In many cases, unused pins may should be connected externally or configured correctly by software to minimize the overall power consumption of the part.

Unused pins with GPIO function should be configured as outputs set to LOW with their internal pull-up disabled. To configure a GPIO pin as output and drive it LOW, select the GPIO function in the IOCON register, select output in the GPIO DIR register, and write a 0 to the GPIO PORT register for that pin. Disable the pull-up in the pin's IOCON register.

In addition, it is recommended to configure all GPIO pins that are not bonded out on smaller packages as outputs driven LOW with their internal pull-up disabled.

Table 19.         Termination of	unused p	ns
Pin	Default state <sup>[1]</sup>	Recommended termination of unused pins
RESET/PIO0_0	I; PU	In an application that does not use the $\overline{\text{RESET}}$ pin or its GPIO function, the termination of this pin depends on whether Deep power-down mode is used:
		<ul> <li>Deep power-down used: Connect an external pull-up resistor and keep pin in default state (input, pull-up enabled) during all other power modes.</li> </ul>
		<ul> <li>Deep power-down not used and no external pull-up connected: can be left unconnected if internal pull-up is disabled and pin is driven LOW and configured as output by software.</li> </ul>
all PIOn_m (not open-drain)	I; PU	Can be left unconnected if driven LOW and configured as GPIO output with pull-up disabled by software.
PIOn_m (I2C open-drain)	IA	Can be left unconnected if driven LOW and configured as GPIO output by software.
VREFP	-	Tie to VDD.
VREFN	-	Tie to VSS.

#### able 10

[1] I = Input, O = Output, IA = Inactive (no pull-up/pull-down enabled), F = floating, PU = Pull-Up.

# 13.6 Pin states in different power modes

#### Table 20. Pin states in different power modes

Pin	Active	Sleep	Deep-sleep/Power- down	Deep power-down
PIOn_m pins (not I2C)	As configured in th enabled.	e IOCON <sup>[1]</sup> . Defau	Ilt: internal pull-up	Floating.
PIO0_4, PIO0_5 (open-drain I2C-bus pins)	As configured in the IOCON <sup>[1]</sup> .		Floating.	
RESET	Reset function enabled. Default: input, internal pull-up enabled.		Reset function disabled; floating; if the part is in deep power-down mode, the RESET pin needs an external pull-up to reduce power consumption.	
PIO1_4/ WAKEUP	As configured in the IOCON <sup>[1]</sup> . WAKEUP function inactive.		Wake-up function enabled; can be disabled by software.	

[1] Default and programmed pin states are retained in sleep, deep-sleep, and power-down modes.

#### 32-bit ARM Cortex-M0 microcontroller

# 13.7 Standard I/O pad configuration

Figure 27 shows the possible pin modes for standard I/O pins with analog input function:

- Digital output driver.
- Digital input: Pull-up enabled/disabled.
- Digital input: Pull-down enabled/disabled.
- Digital input: Repeater mode enabled/disabled.
- Digital output: Pseudo open-drain mode enable/disabled.
- Analog input.



32-bit ARM Cortex-M0 microcontroller

# 13.8 Reset pad configuration



# LPC112x

32-bit ARM Cortex-M0 microcontroller

# 14. Package outline



#### Fig 29. LQFP48 package outline

All information provided in	n this	document is	s subject to	legal	disclaimers.

LPC112x

32-bit ARM Cortex-M0 microcontroller

# 15. Soldering



32-bit ARM Cortex-M0 microcontroller

# 16. Abbreviations

Table 21. Abbreviations				
Acronym	Description			
ADC	Analog-to-Digital Converter			
AHB	Advanced High-performance Bus			
APB	Advanced Peripheral Bus			
BOD	BrownOut Detection			
GPIO	General Purpose Input/Output			
PLL	Phase-Locked Loop			
RC	Resistor-Capacitor			
SPI	Serial Peripheral Interface			
SSI	Serial Synchronous Interface			
SSP	Synchronous Serial Port			
TEM	Transverse ElectroMagnetic			
UART	Universal Asynchronous Receiver/Transmitter			

# **17. References**

- [1] User manual UM10839.
- [2] Errata sheet ES\_LPC112x.
- [3] I2C-bus specification UM10204.
- [4] Technical note ADC design guidelines: http://www.nxp.com/documents/technical\_note/TN00009.pdf

# 32-bit ARM Cortex-M0 microcontroller

# **18. Revision history**

#### Table 22.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
LPC112x v.1.0	20150224	Product data sheet	-	-

# **19. Legal information**

# **19.1 Data sheet status**

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

### **19.2 Definitions**

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

# **19.3 Disclaimers**

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

© NXP Semiconductors N.V. 2015. All rights reserved.

LPC112x

### 32-bit ARM Cortex-M0 microcontroller

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Non-automotive qualified products** — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b)

# 20. Contact information

whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

# 19.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

I<sup>2</sup>C-bus — logo is a trademark of NXP Semiconductors N.V.

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

### 32-bit ARM Cortex-M0 microcontroller

# 21. Contents

1	General description 1
2	Features and benefits 1
3	Applications 2
4	Ordering information 2
4.1	Ordering options
5	Block diagram 4
6	Pinning information
6.1	Pinning
6.2	Pin description
7	Functional description 11
7.1	ARM Cortex-M0 processor
7.2	On-chip flash program memory
7.3	On-chip SRAM
7.4	Memory map 11
7.5	Nested Vectored Interrupt Controller
	(NVIC) 12
7.5.1	Features
7.5.2	Interrupt sources 13
7.6	IOCON block 13
7.7	Fast general purpose parallel I/O 13
7.7.1	Features
7.8	UART 14
7.8.1	Features
7.9	SSP controller
7.9.1	Features
7.10 7.10.1	I <sup>2</sup> C-bus serial I/O controller
7.10.1	Analog-to-Digital Converter
7.11	(ADC)
7.11.1	Features
7.12	General purpose external event
	counter/timers
7.12.1	Features 16
7.13	System tick timer 16
7.14	Windowed WatchDog Timer
7.14.1	Features 16
7.15	Clocking and power control 17
7.15.1	Crystal oscillators 17
7.15.1.1	Internal RC oscillator 18
7.15.1.2	System oscillator 18
7.15.1.3	Watchdog oscillator 19
7.15.2	System PLL 19
7.15.3	Clock output
7.15.4	Wake-up process
7.15.5 7.15.5.1	Power control
7.15.5.1	Power profiles
1.10.0.2	

7.15.5.3		20
7.15.5.4	Deep power-down mode	20
7.16	System control	20
7.16.1	Start logic	20
7.16.2	Reset	21
7.16.3	Brownout detection	21
7.16.4	Code security	
	(Code Read Protection - CRP)	21
7.16.5	APB interface	22
7.16.6	AHBLite	22
7.16.7	External interrupt inputs	22
7.17	Emulation and debugging	22
8	Limiting values	23
9	Thermal characteristics	24
10	Static characteristics	25
10.1	Power consumption	30
10.2	CoreMark data	32
10.3	Peripheral power consumption	34
10.4	Electrical pin characteristics	35
11	Dynamic characteristics	38
11.1	Flash memory	38
11.2	External clock	38
11.3	Internal oscillators	39
11.4	I/O pins	40
11.5	l <sup>2</sup> C-bus	41
11.6	SSP interfaces	42
12	Analog characteristics	45
12.1	BOD static characteristics	45
12.2	12-bit ADC	46
13	Application information	49
13.1	ADC usage notes	49
13.2	XTAL input	49
13.3	XTAL Printed Circuit Board (PCB) layout	
	guidelines	50
13.4	Connecting power, clocks, and debug	
	functions	51
13.5	Termination of unused pins	53
13.6	Pin states in different power modes	53
13.7	Standard I/O pad configuration	
13.8	Reset pad configuration	55
14	Package outline	56
15	Soldering	57
16	Abbreviations	58
17	References	58
18	Revision history	59

#### continued >>

# LPC112x

### 32-bit ARM Cortex-M0 microcontroller

19	Legal information 60
19.1	Data sheet status 60
19.2	Definitions 60
19.3	Disclaimers 60
19.4	Trademarks 61
20	Contact information
21	Contents 62

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

#### © NXP Semiconductors N.V. 2015.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 24 February 2015 Document identifier: LPC112x

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for ARM Microcontrollers - MCU category:

Click to view products by NXP manufacturer:

Other Similar products are found below :

R7FS3A77C2A01CLK#AC1\_CP8363AT\_MB96F119RBPMC-GSE1\_MB9BF122LPMC1-G-JNE2\_MB9BF122LPMC-G-JNE2 MB9BF128SAPMC-GE2\_MB9BF218TBGL-GE1\_MB9BF529TBGL-GE1\_26-21/R6C-AT1V2B/CT\_5962-8506403MQA MB9AF342MAPMC-G-JNE2\_MB96F001YBPMC1-GSE1\_MB9BF121KPMC-G-JNE2\_VA10800-D000003PCA\_CP8547AT CY9AF156NPMC-G-JNE2\_MB9BF104NAPMC-G-JNE1\_CY8C4724FNI-S402T\_ADUCM410BCBZ-RL7\_GD32f303RGT6 NHS3152UK/A1Z\_MK26FN2M0CAC18R\_EFM32TG230F32-D-QFN64\_EFM32TG232F32-D-QFP64\_EFM32TG825F32-D-BGA48 MB9AFB44NBBGL-GE1\_MB9BF304RBPMC-G-JNE2\_MB9BF416RPMC-G-JNE2\_MB9AF155MABGL-GE1\_MB9BF306RBPMC-G-JNE2 MB9BF618TBGL-GE1\_ATSAMS70N21A-CN\_MK20DX64VFT5\_MK50DX128CMC7\_MK51DN256CMD10\_MK51DX128CMC7 MK53DX256CMD10\_MKL25Z32VFT4\_LPC1754FBD80\_STM32F030K6T6TR\_STM32L073VBT6\_LPC11U24FET48301, AT91M42800A-33AU\_AT91SAM7L64-CU\_ATSAM3N0AA-MU\_ATSAM3N0CA-CU\_ATSAM3SD8BA-MU\_ATSAM4LC2BA-UUR\_ATSAM4LC4BA-MU ATSAM4LS2AA-MU